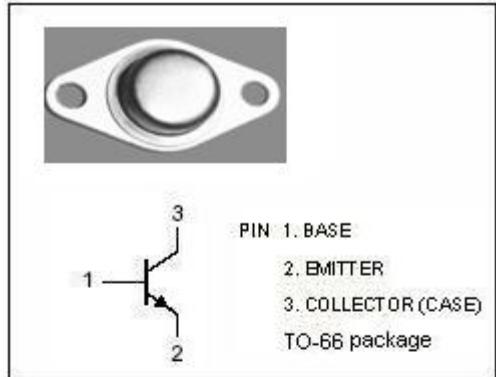


## isc Silicon NPN Power Transistor

**2SD254**

### DESCRIPTION

- Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)\text{CEO}} = 70\text{V}(\text{Min})$
- Collector Power Dissipation-  
:  $P_C = 20\text{W} @ T_C = 25^\circ\text{C}$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

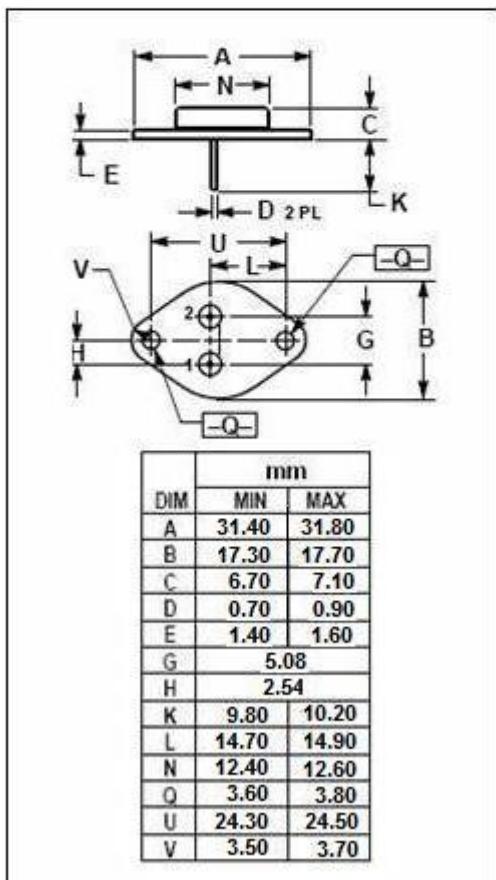


### APPLICATIONS

- Designed for use in general purpose amplifier and switching applications.

### ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	70	V
$V_{CEO}$	Collector-Emitter Voltage	70	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_c$	Collector Current-Continuous	3.0	A
$I_{CM}$	Collector Current-Peak	5.0	A
$I_B$	Base Current	1.0	A
$P_C$	Collector Power Dissipation@ $T_C=25^\circ\text{C}$	20	W
$T_J$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature	-65~150	°C



**isc Silicon NPN Power Transistor****2SD254****ELECTRICAL CHARACTERISTICS****T<sub>c</sub>=25°C unless otherwise specified**

<b>SYMBOL</b>	<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>MIN</b>	<b>MAX</b>	<b>UNIT</b>
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 30mA ; I <sub>B</sub> = 0	70		V
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 0.5A; I <sub>B</sub> = 50mA		1.0	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 1A		2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 2A; V <sub>CE</sub> = 4V		1.8	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 70V; V <sub>EB</sub> = 0		0.1	mA
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = 70V; I <sub>B</sub> = 0		0.3	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0		0.1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 2V	30	200	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 2A ; V <sub>CE</sub> = 2V	15		
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 10V	10		MHz